TPS62095 4A，高效降压转换器，具有 DCS-Control™ 功能和低截面解决方案

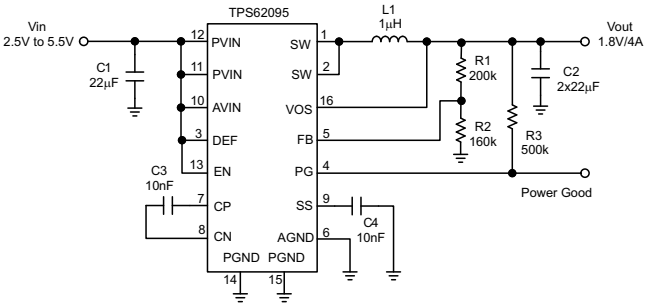
1 特性

- DCS-Control™ 拓扑技术
- 与 TPS62090 引脚到引脚兼容
- 支持高度为 1.2mm 的总体解决方案
- 转换器效率 95%
- 20µA 运行静态电流
- 2.5V 至 5.5V 输入电压范围
- 省电模式
- 两级短路保护
- 100% 占空比，以实现最低压降
- 输出放电功能
- 可调软启动
- 输出电压跟踪
- 0.8V 至 V_{IN} 的可调输出电压
- 3mm x 3mm 16 引脚超薄四方扁平无引线 (VQFN) 封装

2 应用范围

- 笔记本、计算机
- 固态硬盘
- 机械硬盘
- 处理器电源
- 电池供电类应用

1.8V 输出应用



3 说明

TPS62095 器件是一款高频同步降压转换器，此转换器针对小解决方案尺寸、高效率进行了优化并适合于电池供电类应用。 为了最大限度地提升效率，此转换器以 1.4MHz 的标称开关频率运行在脉宽调制 (PWM) 模式下并在轻负载电流时自动进入省电运行模式。 当被用于分布式电源和负载点稳压时，此器件允许到其它电压轨的电压跟踪并可耐受高达 150µF 甚至更高的输出电容器。 通过使用 DCS-Control™ 技术，此器件可实现出色的负载静态性能以及精确的输出电压调节。

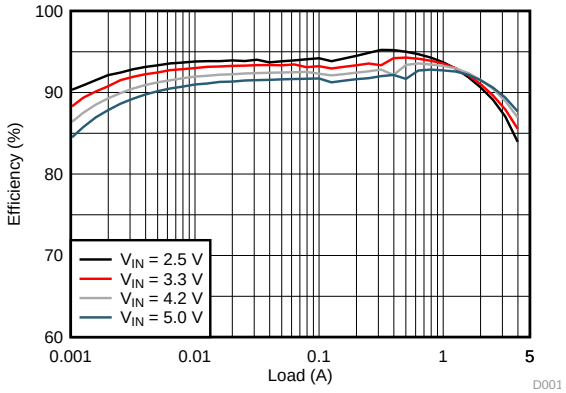
输出电压启动斜坡由软启动引脚控制，从而允许作为独立电源或者在跟踪配置下的运行。 通过配置 EN 和 PG 引脚还可实现电源排序。 在省电模式下，此器件运行时的静态电流典型值为 20µA。 在整个负载电流范围内，自动进入省电模式并且无缝保持高效率。

器件信息(1)

产品型号	封装	封装尺寸（标称值）
TPS62095	VQFN (16)	3.00mm x 3.00mm

(1) 如需了解所有可用封装，请见数据表末尾的可订购产品附录。

1.8V 输出应用效率



PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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4 修订历史记录

Changes from Original (April 2014) to Revision A **Page**

- 已更改 状态从产品预览更改为生产数据 - 已删除产品预览大字标题 ... 1

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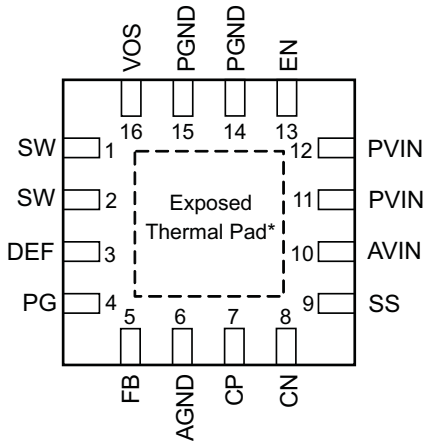
5 Pin Configuration and Functions

16-Pin VQFN with Thermal PAD
RGT
(Top View)



Pin Functions

PIN		DESCRIPTION
NAME	NO.	
SW	1, 2	Switch pin of the power stage.
DEF	3	This pin is used for internal logic and needs to be pulled high. This pin must be connected to the AVIN pin.
PG	4	Power good open drain output. A pull up resistor can not be connected to any voltage higher than the input voltage.
FB	5	Feedback pin, for regulating the output voltage.
AGND	6	Analog ground.
CP	7	Internal charge pump's flying capacitor. Connect a 10nF capacitor between CP and CN.
CN	8	Internal charge pump's flying capacitor. Connect a 10nF capacitor between CP and CN.
SS	9	Soft-start control pin. A capacitor is connected to this pin and sets the soft startup time. Leaving this pin floating sets the minimum start-up time.
AVIN	10	Analog supply input voltage pin.
PVIN	11,12	Power supply input voltage pin.
EN	13	Enable pin. This pin has an active pull down resistor of typically 400kΩ.
PGND	14,15	Power ground.
VOS	16	Output voltage sense pin. This pin must be directly connected to the output voltage.
Thermal Pad		The exposed thermal pad must be connected to AGND.

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6 Specifications

6.1 Absolute Maximum Ratings(1)

		MIN	MAX	UNIT
Voltage at pins(2)	PVIN, AVIN, FB, SS, EN, DEF, VOS	-0.3	7.0	V
	SW, PG	-0.3	V_{IN}+0.3	
Sink current	PG		1.0	mA
Operating junction temperature		-40	150	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values are with respect to network ground pin.

6.2 Handling Ratings

			MIN	MAX	UNIT
T_{stg}	Storage temperature range		–65	150	°C
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	0	2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins(2)	0	500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommend Operating Conditions

Over operating free-air temperature range, unless otherwise noted.

		MIN	MAX	UNIT
V_{IN}	Input voltage range	2.5	5.5	V
V_{PG}	Power good pull-up resistor voltage		V_{IN}	V
V_{OUT}	Output voltage range	0.8	V_{IN}	V
I_{OUT}	Output current range	0	4.0	A
T_J	Operating junction temperature	-40	125	°C

6.4 Thermal Information

THERMAL METRIC(1)		RGT (16 PINS)	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	47	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	60	
$R_{\theta JB}$	Junction-to-board thermal resistance	20	
ψ_{JT}	Junction-to-top characterization parameter	1.5	
ψ_{JB}	Junction-to-board characterization parameter	20	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	5.3	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953

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6.5 Electrical Characteristics

V_{IN} = 3.6V, T_A = –40°C to 85°C, typical values are at T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
V_{IN}	Input voltage range		2.5		5.5	V
I_{QIN}	Quiescent current	Not switching, No Load, Into PVIN and AVIN		20		µA
I_{sd}	Shutdown current	Into PVIN and AVIN		0.6	5	µA
UVLO	Undervoltage lockout threshold	V_{IN} falling	2.1	2.2	2.3	V
	Undervoltage lockout hysteresis			200		mV
	Thermal shutdown	Temperature rising		150		ºC
	Thermal shutdown hysteresis			20		ºC
CONTROL SIGNAL EN						
V_H	High level input voltage	V_{IN} = 2.5 V to 5.5 V	1			V
V_L	Low level input voltage	V_{IN} = 2.5 V to 5.5 V			0.4	V
I_{lkg}	Input leakage current	EN = V_{IN}		10	100	nA
R_{PD}	Pull down resistance	EN = Low		400		kΩ
SOFT STARTUP						
I_{SS}	Softstart current		6.3	7.5	8.7	µA
POWER GOOD						
V_{th}	Power good threshold	Output voltage rising	93%	95%	97%	
		Output voltage falling	88%	90%	92%	
V_L	Low level voltage	$I_{(sink)}$ = 1 mA			0.4	V
I_{lkg}	Leakage current	V_{PG} = 3.6 V		10	100	nA
POWER SWITCH						
$R_{DS(on)}$	High side FET on-resistance	I_{SW} = 500 mA		50		mΩ
	Low side FET on-resistance	I_{SW} = 500 mA		40		mΩ
I_{LIM}	High side FET switch current limit		4.7	5.5	6.7	A
f_{SW}	Switching frequency	I_{OUT} = 3 A		1.4		MHz
OUTPUT						
V_{OUT}	Output voltage range		0.8		V_{IN}	V
R_{DIS}	Output discharge resistor	EN = GND, V_{OUT} = 1.8 V		200		Ω
V_{FB}	Feedback regulation voltage			0.8		V
	Feedback voltage accuracy (1)	I_{OUT} = 1 A, PWM mode	-1.4%		+1.4%	
		I_{OUT} = 1 mA, PFM mode, V_{OUT} ≥ 1.8 V	-1.4%		+2.0%	
		I_{OUT} = 1 mA, PFM mode, V_{OUT} < 1.8 V	-1.4%		+2.5%	
I_{FB}	Feedback input bias current	V_{FB} = 0.8 V		10	100	nA
	Line regulation	V_{OUT} = 1.8 V, PWM operation		0.016		%/V
	Load regulation	V_{OUT} = 1.8 V, PWM operation		0.04		%/A

(1) Conditions: L = 1 µH, C_{OUT} = 2 x 22 µF.

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6.6 Typical Characteristics

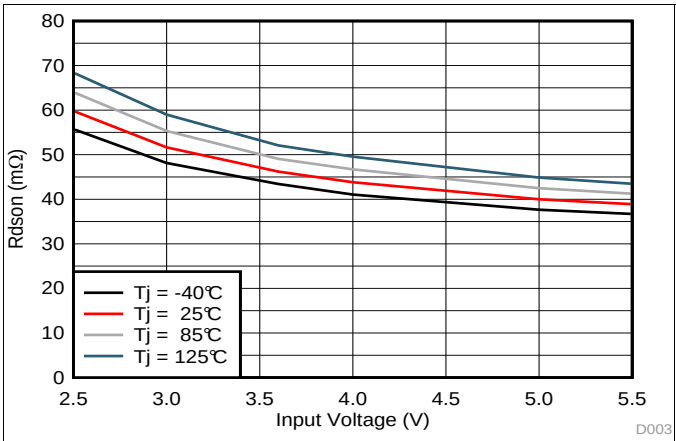

Figure 1. High Side FET On Resistance

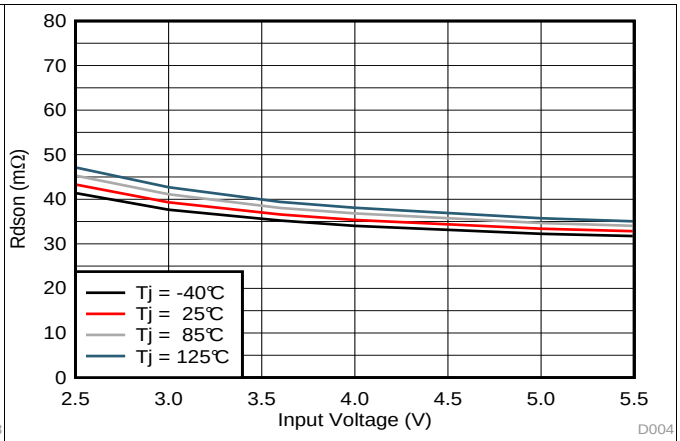

Figure 2. Low Side FET On Resistance

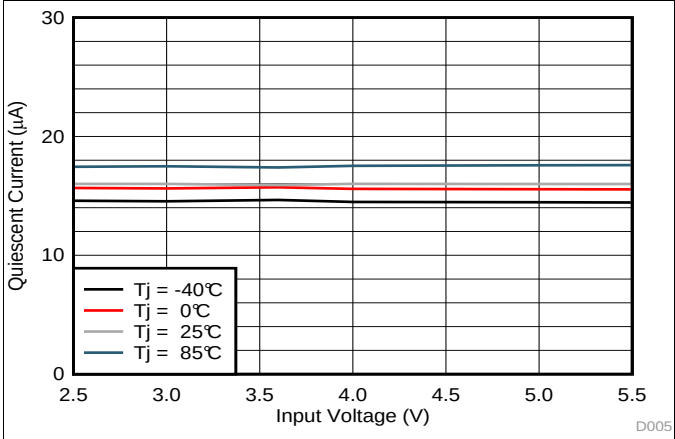

Figure 3. Quiescent Current

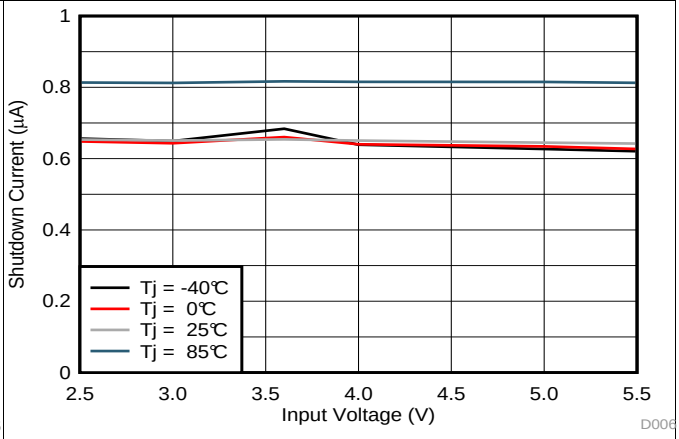

Figure 4. Shutdown Current

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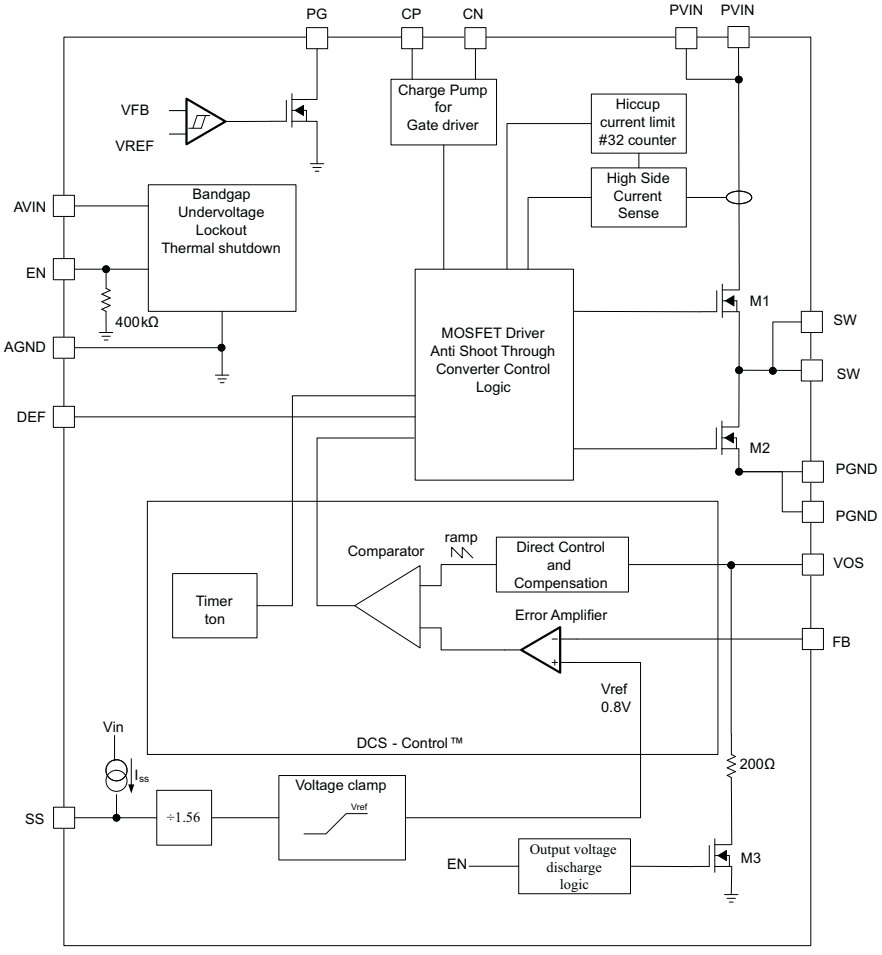
7 Detailed Description

7.1 Overview

The TPS62095 synchronous step down converter is based on DCS-Control™ (Direct Control with Seamless transition into Power Save Mode). This is an advanced regulation topology that combines the advantages of hysteretic and voltage mode control.

The DCS-Control™ topology operates in PWM (Pulse Width Modulation) mode for medium to heavy load conditions and in Power Save Mode at light load currents. In PWM, the converter operates with its nominal switching frequency of 1.4 MHz having a controlled frequency variation over the input voltage range. As the load current decreases, the converter enters Power Save Mode, reducing the switching frequency and minimizing the IC's quiescent current to achieve high efficiency over the entire load current range. DCS-Control™ supports both operation modes using a single building block and therefore has a seamless transition from PWM to Power Save Mode without effects on the output voltage. The TPS62095 offers excellent DC voltage regulation and load transient regulation, combined with low output voltage ripple, minimizing interference with RF circuits.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 PWM Operation

In PWM mode, the device operates with a fixed ON-time switching pulse at medium to heavy load currents. A quasi fixed switching frequency of typical 1.4MHz over the input and output voltage range is achieved by using an input feed forward. The ON-time is calculated as shown in Equation 2. As the load current decreases, the converter enters Power Save Mode operation reducing its switching frequency. The device enters Power Save Mode at the boundary to discontinuous conduction mode (DCM).

7.3.2 Low Dropout Operation (100% Duty Cycle)

The device offers low input to output voltage difference by entering 100% duty cycle mode. In this mode the high side MOSFET switch is constantly turned on. This is particularly useful in battery powered applications to achieve longest operation time by taking full advantage of the whole battery voltage range. The minimum input voltage where the output voltage falls below set point is given by:

$$V_{IN(min)} = V_{OUT(min)} + I_{OUT} \times (R_{DS(on)} + R_L) \quad (1)$$

Where

$R_{DS(on)}$ = High side FET on-resistance

R_L = DC resistance of the inductor

$V_{OUT(min)}$ = Minimum output voltage the load can accept

7.3.3 Power Save Mode Operation

As the load current decreases, the converter enters Power Save Mode operation. During Power Save Mode, the converter operates with reduced switching frequency and with a minimum quiescent current to maintain high efficiency. The Power Save Mode is based on a fixed on-time architecture following Equation 2.

$$ton = \frac{V_{OUT}}{V_{IN}} \times 360ns \times 2$$

$$f = \frac{2 \times I_{OUT}}{ton^2 \left(1 + \frac{V_{IN} - V_{OUT}}{V_{OUT}} \right) \times \frac{V_{IN} - V_{OUT}}{L}} \quad (2)$$

In Power Save Mode, the output voltage rises slightly above the nominal output voltage in PWM mode. This effect is reduced by increasing the output capacitance or the inductor value. This effect is also reduced by programming the output voltage of the TPS62095 lower than the target value. As an example, if the target output voltage is 3.3V, then the TPS62095 can be programmed to 3.3V - 0.3%. As a result, the output voltage accuracy is now -1.7% to +1.7% instead of -1.4% to 2%. The output voltage accuracy in PFM operation is reflected in the electrical specification table and given for a 2 x 22µF output capacitance.

7.4 Device Functional Modes

7.4.1 Soft Startup

To minimize inrush current during startup, the device has an adjustable startup time depending on the capacitor value connected to the SS pin. The device charges the SS capacitor with a constant current of typically 7.5µA. The feedback voltage follows this voltage divided by 1.56, until the internal reference voltage of 0.8V is reached. The soft startup operation is completed once the voltage at the SS capacitor has reached typically 1.25V. The soft startup time is calculated using Equation 3. The larger the SS capacitor, the longer the soft startup time. The relation between the SS pin voltage and the FB pin voltage is estimated using Equation 4. Leaving the SS pin floating sets the minimum startup time.

$$t_{SS} = C_{SS} \times \frac{1.25V}{7.5\mu A} \quad (3)$$

$$V_{FB} = \frac{V_{SS}}{1.56} \quad (4)$$

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Device Functional Modes (continued)

During startup the switch current limit is reduced to 1/3 of its typical current limit of 5.5A when the output voltage is less than 0.6V. Once the output voltage exceeds typically 0.6V, the switch current limit is released to its nominal value. Thus, the device provides a reduced load current of 1.8A when the output voltage is below 0.6V. A small or no soft startup time may trigger this reduced switch current limit during startup, especially for larger output capacitor applications. This is avoided by using a larger soft start up capacitance which extends the soft startup time. See Short Circuit Protection (Hiccup-Mode) for details of the reduced current limit during startup.

7.4.2 Voltage Tracking

The SS pin can also be used to implement output voltage tracking with other supply rails, as shown in Figure 5.

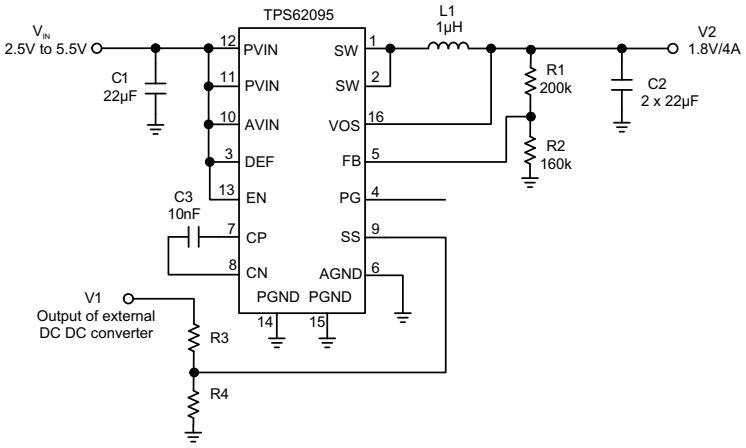

Figure 5. Output Voltage Tracking

In voltage tracking applications, the resistance R4 should be set properly to achieve accurate voltage tracking by taking 7.5µA soft startup current into account. 4.3kΩ is a sufficient value for R4. The relationship between V1 and V2 is shown in Equation 5. To achieve V1 startup leading V2, as shown in Figure 6, Equation 5 should be less than 1. To achieve simultaneous tracking, Equation 5 should equal to 1.

$$\frac{V2}{V1} = \frac{1}{1.56} \times \frac{R4}{R3 + R4} \times \frac{R1 + R2}{R2} \quad (5)$$

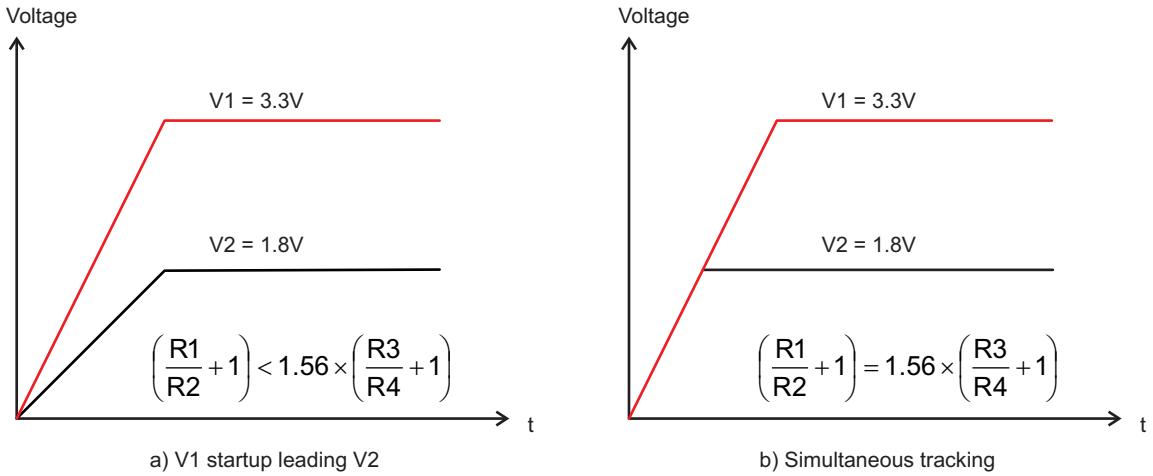

Figure 6. Voltage Tracking Applications

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Device Functional Modes (continued)

7.4.3 Short Circuit Protection (Hiccup-Mode)

The device is protected against hard short circuits to GND and over-current events. This is implemented by a two level short circuit protection. During start-up and when the output is shorted to GND, the switch current limit is reduced to 1/3 of its typical current limit of 5.5A. Once the output voltage exceeds typically 0.6V the current limit is released to its nominal value. The full current limit is implemented as a hiccup current limit. Once the internal current limit is triggered 32 times, the device stops switching and starts a new start-up sequence after a typical delay time of 66µS passed by. The device repeats these cycles until the high current condition is released.

7.4.4 Output Discharge Function

To make sure the device starts up under defined conditions, the output gets discharged via the VOS pin with a typical discharge resistor of 200Ω whenever the device shuts down. This happens when the device is disabled or if thermal shutdown, undervoltage lockout or short circuit hiccup-mode is triggered.

7.4.5 Power Good Output

The power good output is low when the output voltage is below its nominal value. The power good becomes high impedance once the output is within 5% of regulation. The PG pin is an open drain output and is specified to sink up to 1mA. This output requires a pull-up resistor to be monitored properly. The pull-up resistor cannot be connected to any voltage higher than the input voltage of the device.

7.4.6 Undervoltage Lockout

To avoid mis-operation of the device at low input voltages, an undervoltage lockout is included. UVLO shuts down the device at input voltages lower than typically 2.2V with a 200mV hysteresis.

7.4.7 Thermal Shutdown

The device goes into thermal shutdown once the junction temperature exceeds typically 150°C with a 20°C hysteresis.

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8 Application and Implementation

8.1 Application Information

The TPS62095 is a synchronous step down converter based on DCS-Control™ topology whose output voltage can be adjusted by component selection. The following section discusses the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference.

8.2 Typical Applications

8.2.1 2.5V to 5.5V Input, 1.8V Output Converter

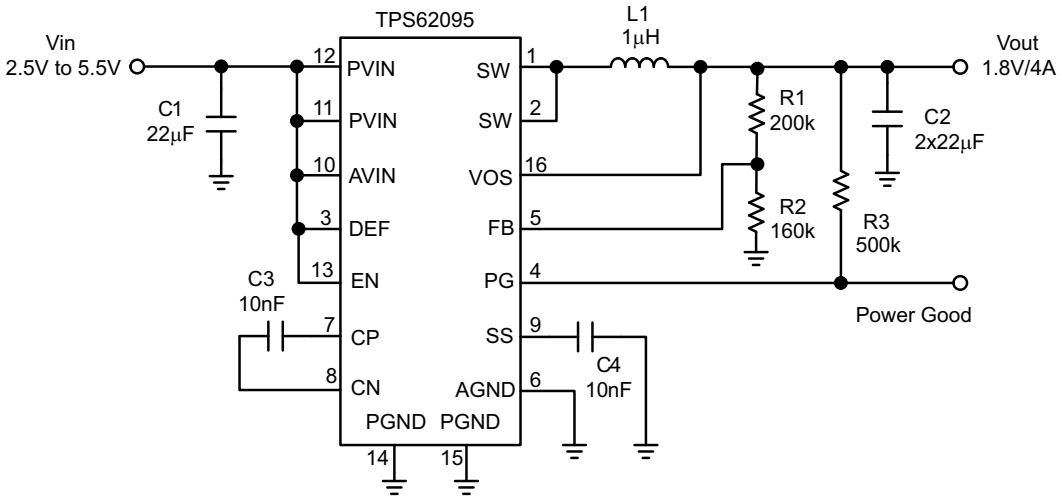

Figure 7. 1.8-V Output Application

8.2.1.1 Design Requirements

For this design example, use the following as the input parameters.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	2.5V to 5.5V
Output voltage	1.8V
Output ripple voltage	<20mV
Output current rating	4A

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8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Output Filter

The first step is the selection of the output filter components. To simplify this process, Table 2 outlines possible inductor and capacitor value combinations.

Table 2. Output Filter Selection

INDUCTOR VALUE [µH](1)	OUTPUT CAPACITOR VALUE [µF](2)				
	10	22	2 x 22	100	150
0.47			√	√	√
1.0			√(3)	√	√
2.2					

(1) Inductor tolerance and current de-rating is anticipated. The effective inductance can vary by +20% and –30%.
(2) Capacitance tolerance and bias voltage de-rating is anticipated. The effective capacitance can vary by +20% and –50%.
(3) Typical application configuration. Other check mark indicates alternative filter combinations

8.2.1.2.2 Inductor Selection

The inductor selection is affected by several parameters like inductor ripple current, output voltage ripple, transition point into Power Save Mode, and efficiency. See Table 3 for typical inductors.

Table 3. Inductor Selection(1)

INDUCTOR VALUE	COMPONENT SUPPLIER	SIZE (LxWxH mm)	Isat / DCR
1 µH	Coilcraft XAL4020-102	4.0 x 4.0 x 2.1	8.75A / 13.2 mΩ
0.47 µH	TOKO DFE322512C	3.2 x 2.5 x 1.2	5.9A / 21 mΩ

(1) See Third-Party Products Disclaimer.

In addition, the inductor has to be rated for the appropriate saturation current and DC resistance (DCR). The inductor needs to be rated for a saturation current as high as the typical switch current limit of 5.5A or according to Equation 6 and Equation 7. Equation 6 and Equation 7 calculate the maximum inductor current under static load conditions. The formula takes the converter efficiency into account. The converter efficiency can be taken from the data sheet graphs or 80% can be used as a conservative approach. The calculation must be done for the maximum input voltage where the peak switch current is highest.

$$I_L = I_{OUT} + \frac{\Delta I_L}{2} \quad (6)$$

$$I_L = I_{OUT} + \frac{\frac{V_{OUT}}{\eta} \times \left(1 - \frac{V_{OUT}}{V_{IN} \times \eta}\right)}{2 \times f \times L} \quad (7)$$

where

f = Converter switching frequency (typically 1.4MHz)
L = Inductor value
η = Estimated converter efficiency (use the number from the efficiency curves or 0.80 as a conservative assumption)

Note: The calculation must be done for the maximum input voltage of the application

Calculating the maximum inductor current using the actual operating conditions gives the minimum saturation current. A margin of 20% should be added to cover for load transients during operation.

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8.2.1.2.3 Input and Output Capacitor Selection

For best output and input voltage filtering, low ESR ceramic capacitors are recommended. The input capacitor minimizes input voltage ripple, suppresses input voltage spikes and provides a stable system rail for the device. A 22µF or larger input capacitor is required. The output capacitor value can range from 2x22µF up to 150µF. The recommended typical output capacitor value is 2x22µF and can vary over a wide range as outline in the output filter selection table.

8.2.1.2.4 Setting the Output Voltage

The output voltage is set by an external resistor divider according to the following equations:

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R1}{R2}\right) = 0.8\ V \times \left(1 + \frac{R1}{R2}\right) \quad (8)$$

$$R2 = \frac{V_{FB}}{I_{FB}} = \frac{0.8\ V}{5\ \mu A} \approx 160\ k\Omega \quad (9)$$

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1\right) = R2 \times \left(\frac{V_{OUT}}{0.8V} - 1\right) \quad (10)$$

When sizing R2, in order to achieve low quiescent current and acceptable noise sensitivity, use a minimum of 5µA for the feedback current I_{FB}. Larger currents through R2 improve noise sensitivity and output voltage accuracy.

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8.2.1.3 Application Performance Curves

T_A = 25°C, V_{IN} = 3.6V, VOUT = 1.8V, L1 = 1µH (XAL4020-102), C2 = 2x22µF, unless otherwise noted.

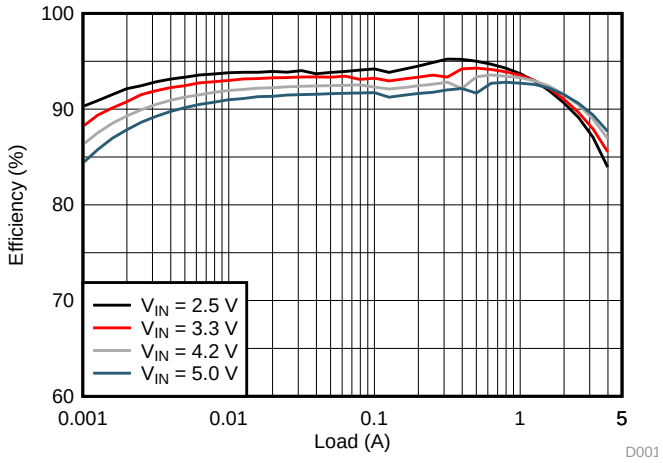

Figure 8. Efficiency, V_{OUT} = 1.8V

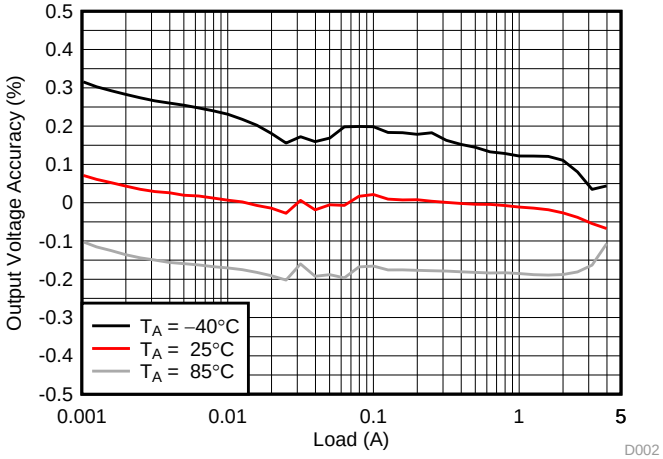

Figure 9. Load Regulation, V_{OUT} = 1.8V, V_{IN} = 3.3V

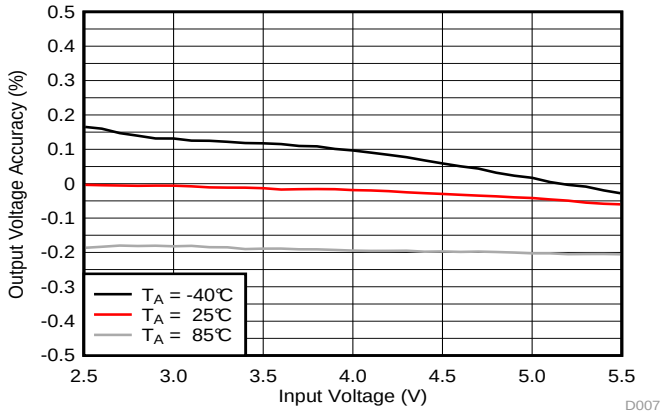

Figure 10. Line Regulation, V_{OUT} = 1.8V, I_{OUT} = 1.0A

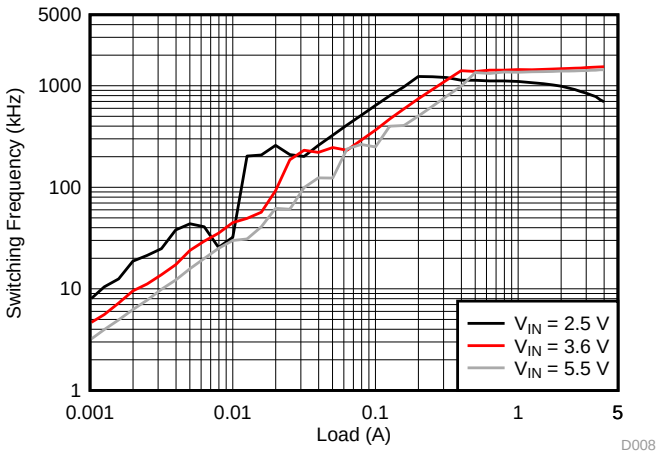

Figure 11. Switching Frequency, V_{OUT} = 1.8V

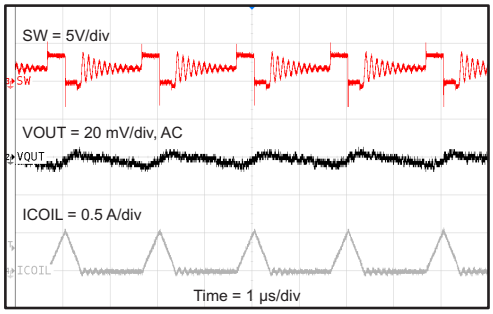

Figure 12. Output Ripple, V_{OUT} = 1.8V, I_{OUT} = 100mA

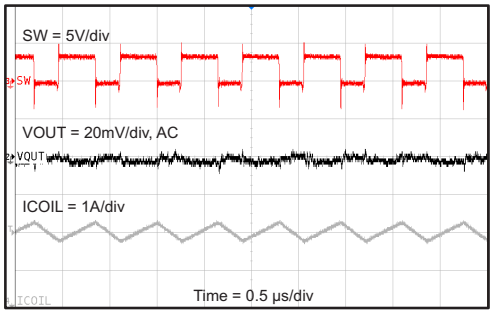

Figure 13. Output Ripple, V_{OUT} = 1.8V, I_{OUT} = 3.5A

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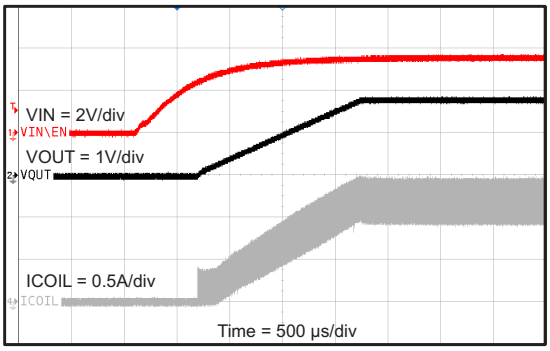

Figure 14. Startup, Relative to V_{IN}, R_{LOAD} = 1.5Ω

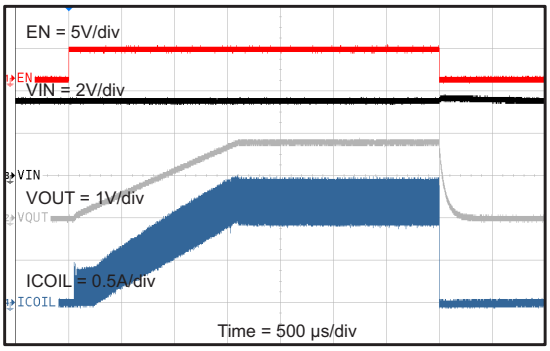

Figure 15. Startup, Relative to EN, R_{LOAD} = 1.5Ω

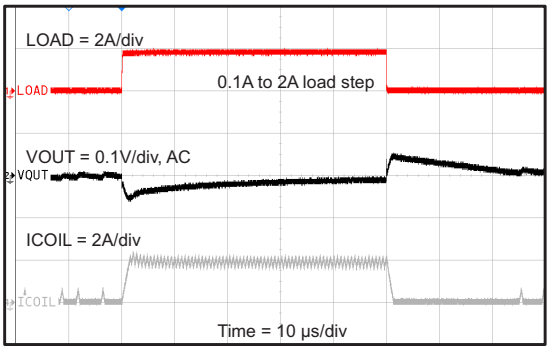

Figure 16. Load Transient, V_{OUT} = 1.8V

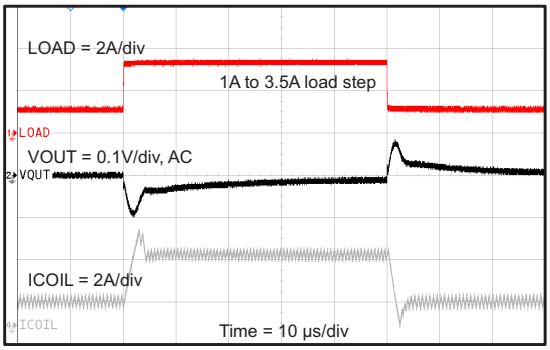

Figure 17. Load Transient, V_{OUT} = 1.8V

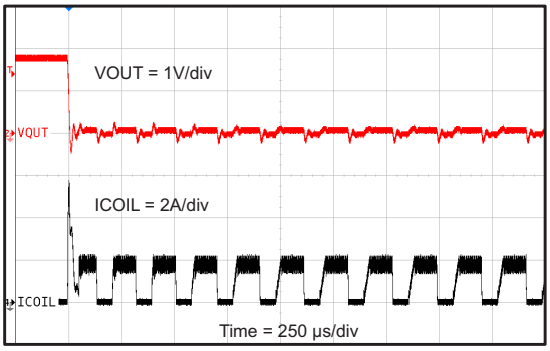

Figure 18. Short Circuit, HICCUP Protection Entry

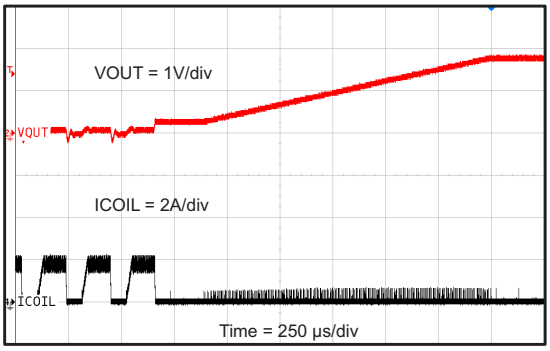

Figure 19. Short Circuit, HICCUP Protection Exit

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8.2.2 2.5V to 5.5V Input, 1.2V Output Converter

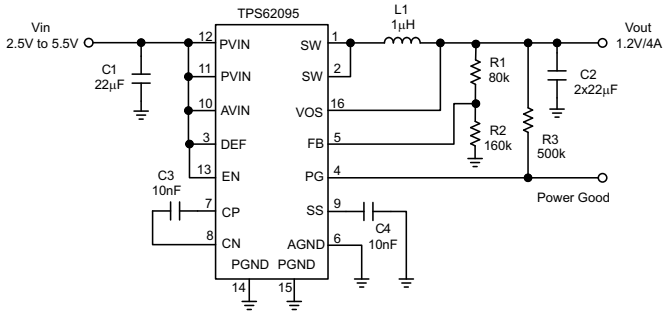

Figure 20. 1.2V Output Application

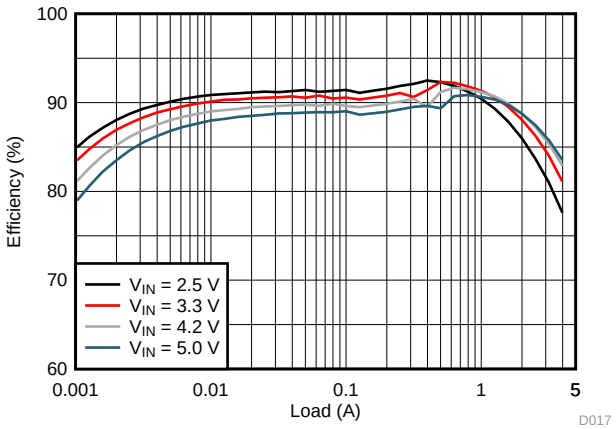

Figure 21. 1.2V Output Application Efficiency

8.2.3 3.0V to 5.5V Input, 2.6V Output Converter

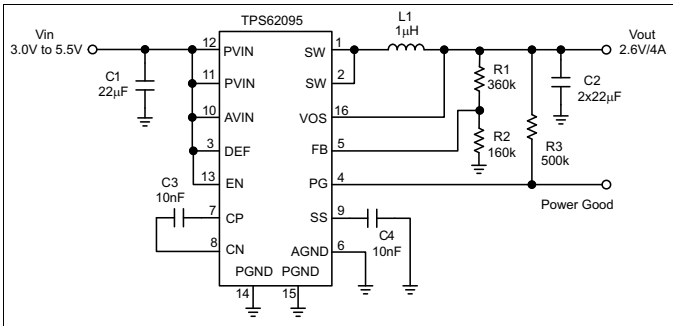

Figure 22. 2.6V Output Application

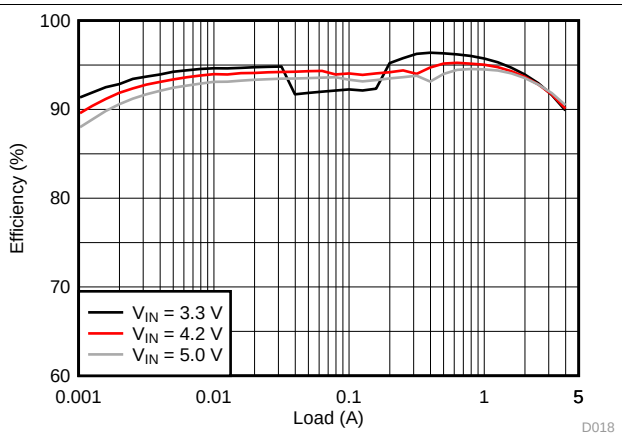

Figure 23. 2.6V Output Application Efficiency

8.2.4 5V Input, 3.3V Output Converter

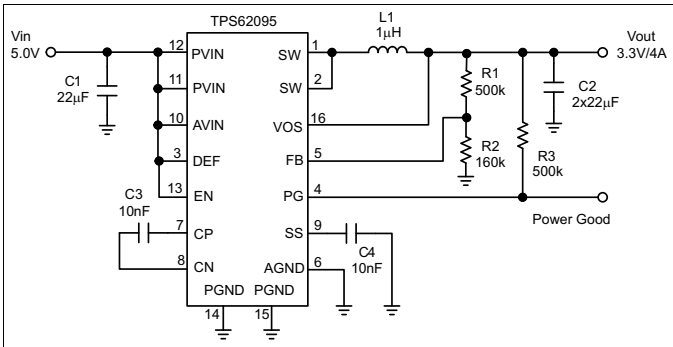

Figure 24. 3.3V Output Application

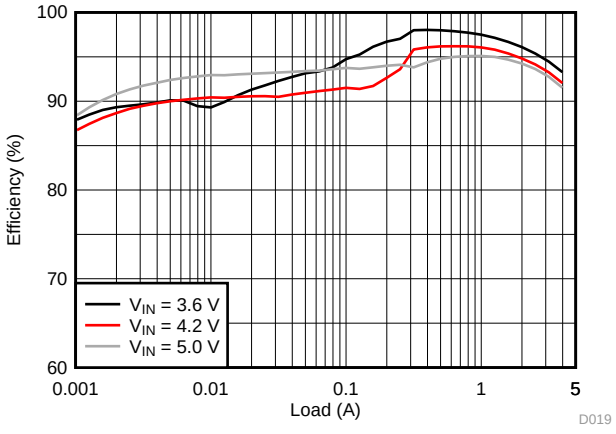

Figure 25. 3.3V Output Application Efficiency

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9 Power Supply Recommendations

The devices are designed to operate from an input voltage supply range between 2.5V and 5.5V. If the input supply is located more than a few inches from the device, an additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 47µF is a typical choice.

The average input current of the TPS62095 is calculated as:

$$I_{IN} = \frac{1}{\eta} \times \frac{V_{OUT} \times I_{OUT}}{V_{IN}} \quad (11)$$

10 Layout

10.1 Layout Guidelines

- It is recommended to place all components as close as possible to the IC. Specially, the input capacitor placement is closest to the PVIN and PGND pins of the device.
- Use wide and short traces for the main current paths to reduce the parasitic inductance and resistance, like the SW node.
- The VOS pin is noise sensitive and needs to be routed as short and directly to the output pin of the inductor and the output capacitor. This minimizes switch node jitter.
- The exposed thermal pad of the package, the AGND and the PGND should have a single joint connection at the exposed thermal pad of the package. To enhance heat dissipation of the device, the exposed thermal pad should be connected to bottom or internal layer ground planes using vias.
- The charge pump capacitor connected to CP and CN should be placed close to the IC to minimize coupling of switching waveforms into other traces and circuits.
- The capacitor on the SS pin and the FB resistors divider network should be placed close to the IC and connected directly to those pins and the AGND pin.
- Refer to Figure 26 for an example of component placement, routing and thermal design.

10.2 Layout Example

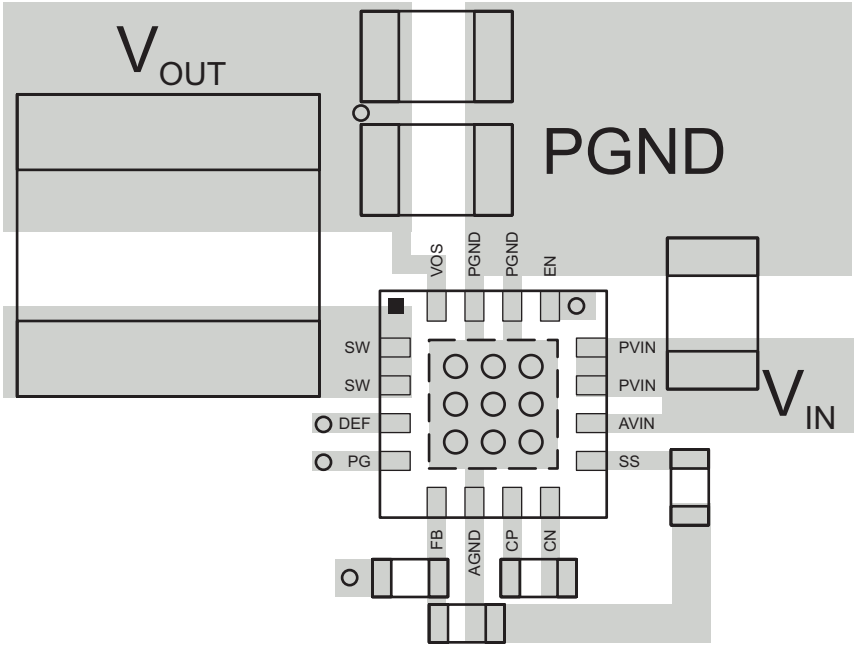

Figure 26. TPS62095 PCB Layout

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10.3 Thermal Consideration

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component. The Thermal Information table provides the thermal metric of the device and its package based on JEDEC standard. For more details on how to use the thermal parameters in real applications, see the application notes: SZZA017 and SPRA953.

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11 器件和文档支持

11.1 器件支持

11.1.1 第三方产品免责声明

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11.2 Trademarks

DCS-Control is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.3 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.4 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械封装和可订购信息

以下页中包括机械封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS62095RGTR	Active	Production	VQFN (RGT) | 16	3000 | LARGE T&R	Yes	FULL NIPDAU | NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SMC
TPS62095RGTR.A	Active	Production	VQFN (RGT) | 16	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SMC
TPS62095RGTR.B	Active	Production	VQFN (RGT) | 16	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SMC
TPS62095RGTRG4	Active	Production	VQFN (RGT) | 16	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SMC
TPS62095RGTRG4.A	Active	Production	VQFN (RGT) | 16	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SMC
TPS62095RGTRG4.B	Active	Production	VQFN (RGT) | 16	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SMC
TPS62095RGTT	Active	Production	VQFN (RGT) | 16	250 | SMALL T&R	Yes	FULL NIPDAU | NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SMC
TPS62095RGTT.A	Active	Production	VQFN (RGT) | 16	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SMC
TPS62095RGTT.B	Active	Production	VQFN (RGT) | 16	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	SMC

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

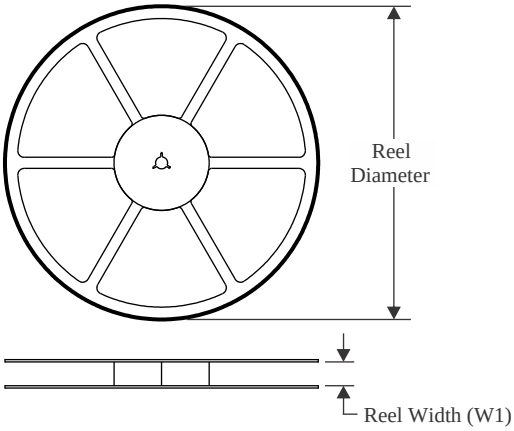
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

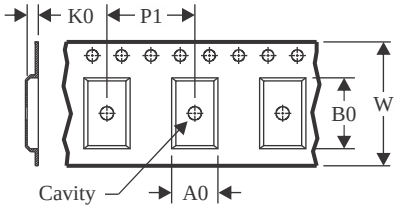
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

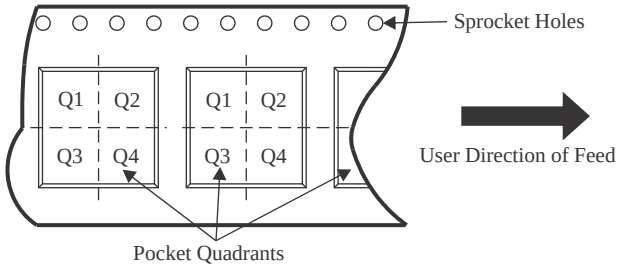


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

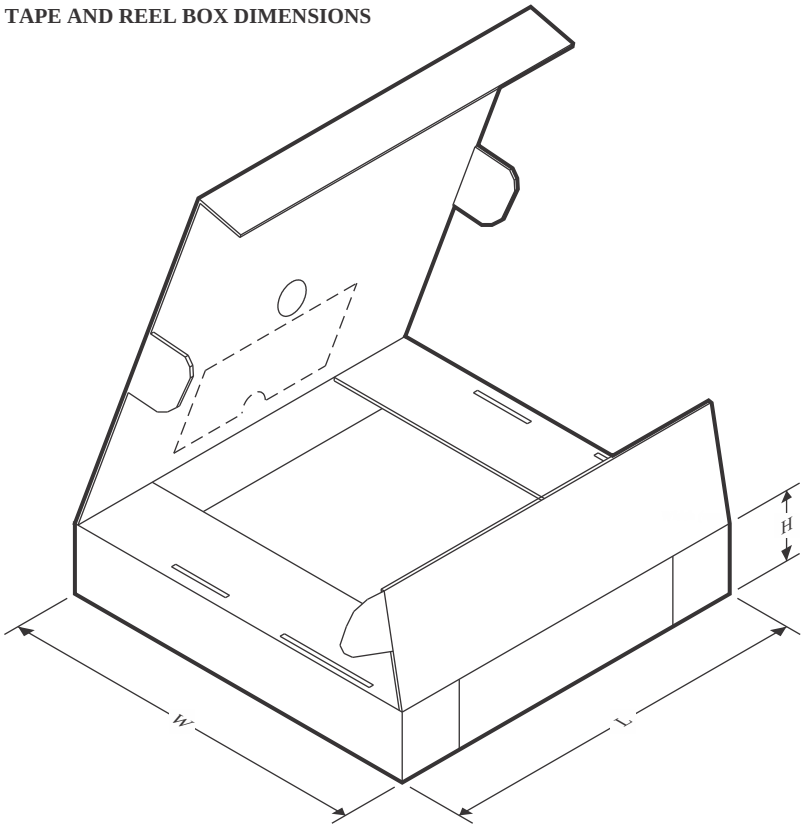
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62095RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS62095RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS62095RGTRG4	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS62095RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS62095RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

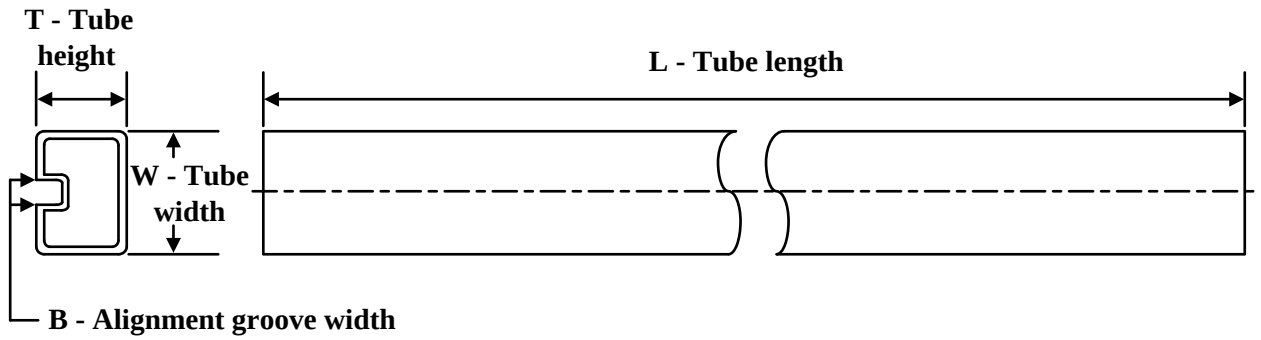
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62095RGTR	VQFN	RGT	16	3000	552.0	346.0	36.0
TPS62095RGTR	VQFN	RGT	16	3000	367.0	367.0	35.0
TPS62095RGTRG4	VQFN	RGT	16	3000	552.0	346.0	36.0
TPS62095RGTT	VQFN	RGT	16	250	210.0	185.0	35.0
TPS62095RGTT	VQFN	RGT	16	250	552.0	185.0	36.0

TUBE



*All dimensions are nominal

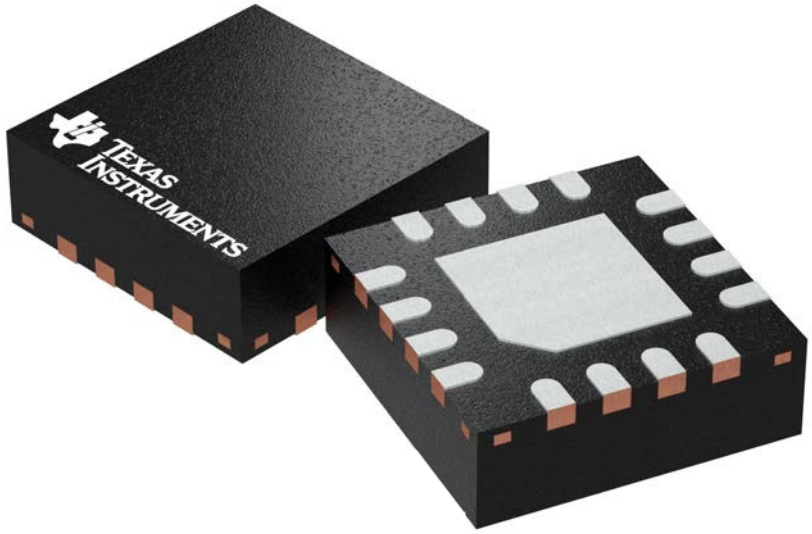
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TPS62095RGTR	RGT	VQFN	16	3000	381	4.83	2286	0
TPS62095RGTR.A	RGT	VQFN	16	3000	381	4.83	2286	0
TPS62095RGTR.B	RGT	VQFN	16	3000	381	4.83	2286	0
TPS62095RGTRG4	RGT	VQFN	16	3000	381	4.83	2286	0
TPS62095RGTRG4.A	RGT	VQFN	16	3000	381	4.83	2286	0
TPS62095RGTRG4.B	RGT	VQFN	16	3000	381	4.83	2286	0
TPS62095RGTT	RGT	VQFN	16	250	381	4.83	2286	0
TPS62095RGTT.A	RGT	VQFN	16	250	381	4.83	2286	0
TPS62095RGTT.B	RGT	VQFN	16	250	381	4.83	2286	0

GENERIC PACKAGE VIEW

RGT 16

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

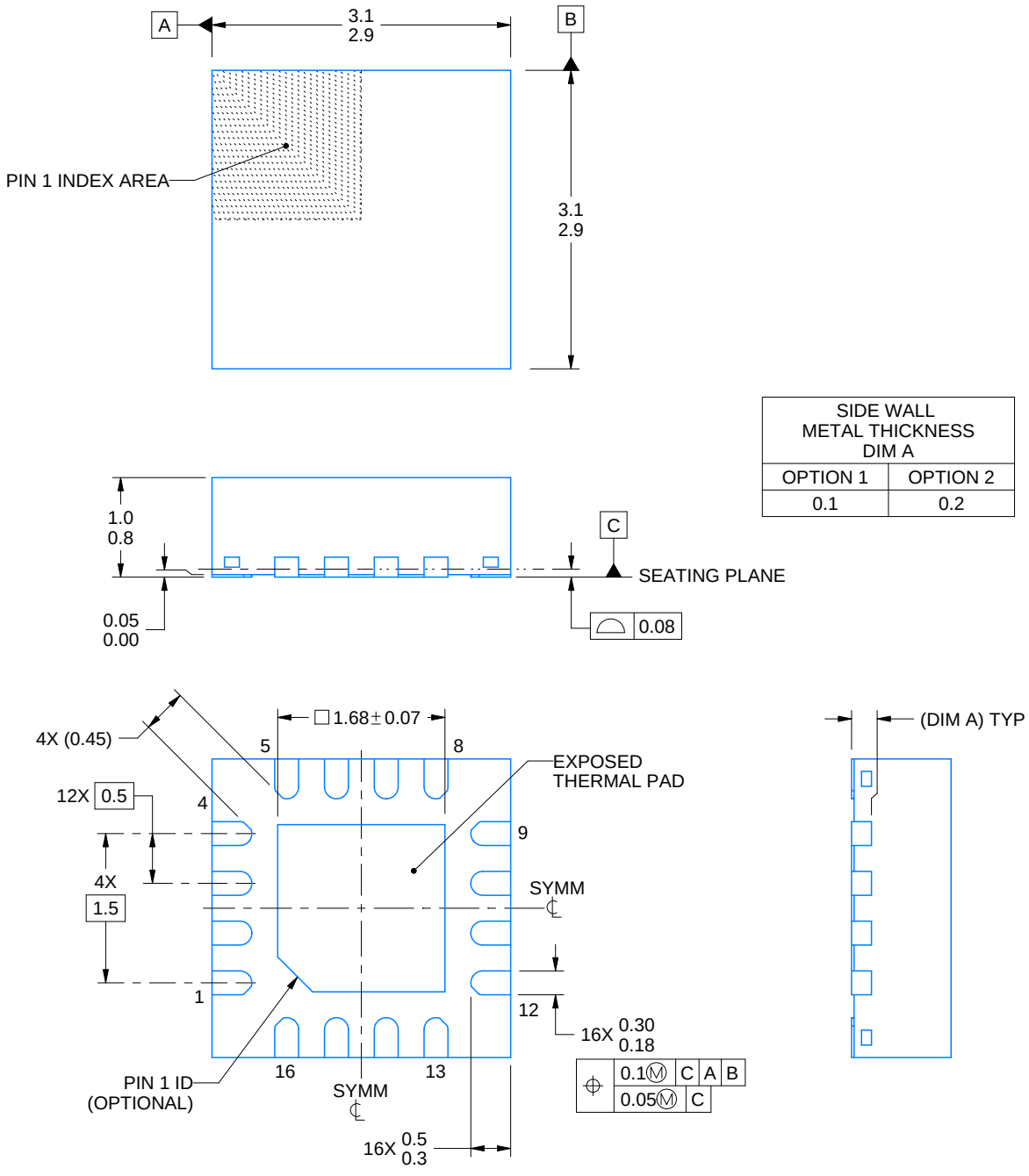
4203495/I

RGT0016C

PACKAGE OUTLINE

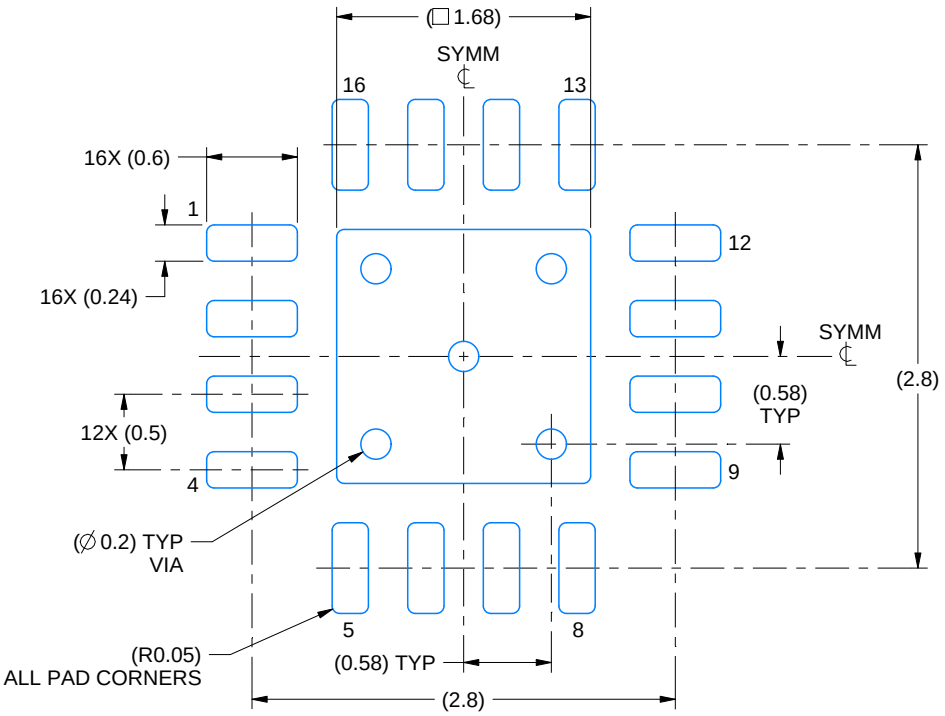
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

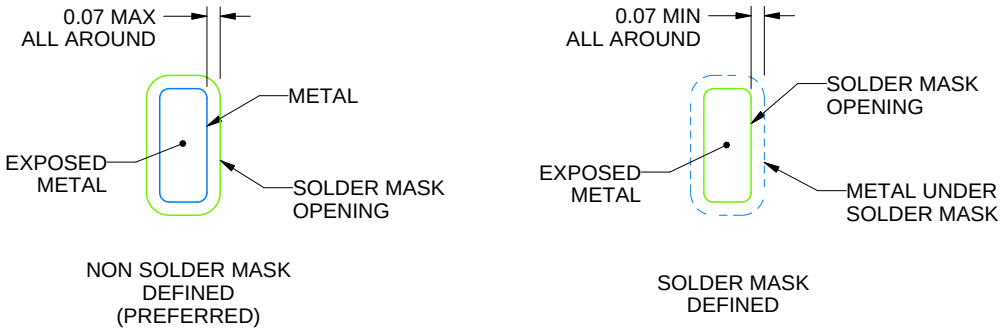


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X

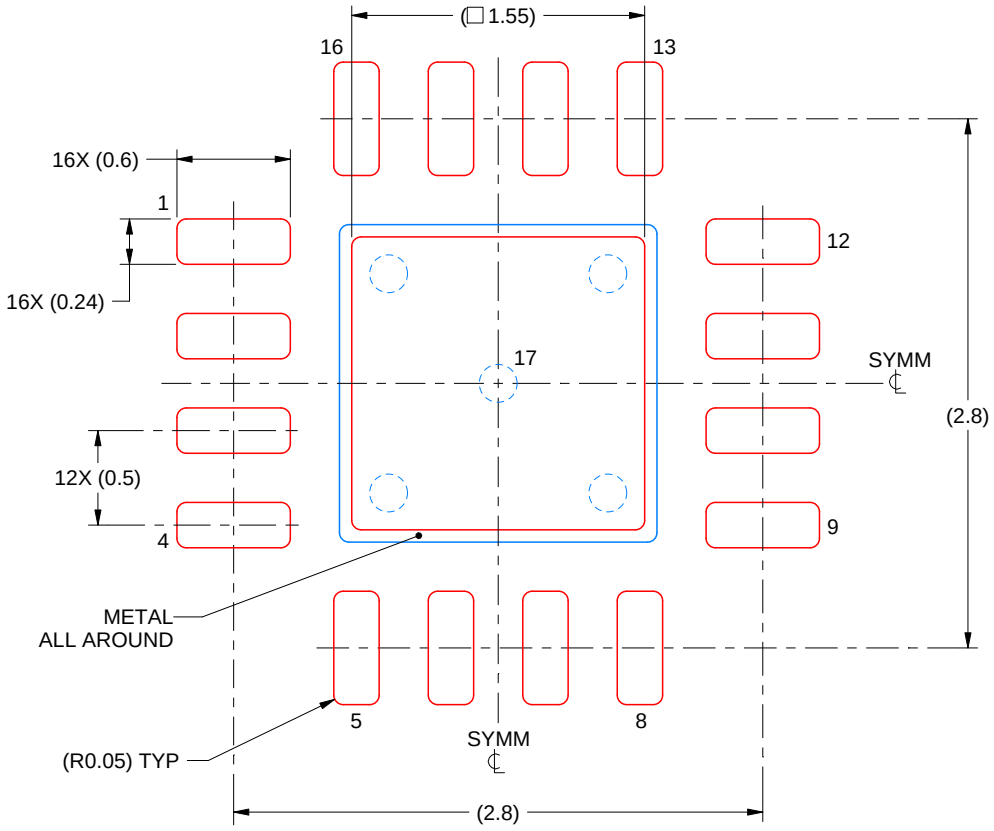


SOLDER MASK DETAILS

4222419/E 07/2025

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
85% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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